

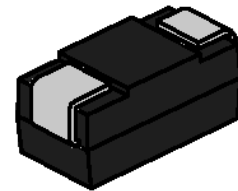


PxxxxTA Series TSS

Rev.4.1

DESCRIPTION:

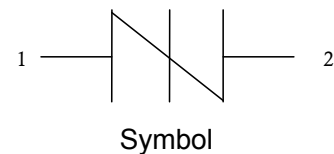
PxxxxTA series are a type of semiconduct component.
They are designed to protect baseband equipment
from damaging overvoltage transients.



SMA

FEATURES:

- ✧ Low profile package.
- ✧ Low on-state voltage.
- ✧ Excellent capability of absorbing transient surge.
- ✧ Quick response to surge voltage (ns Level).
- ✧ Eliminates overvoltage caused by fast rising transients.
- ✧ Moisture sensitivity level: Level 1.
- ✧ Non degenerative.

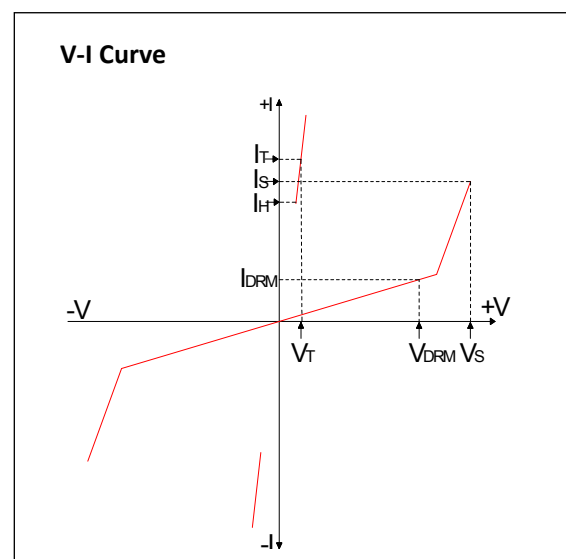


ABSOLUTE MAXIMUM RATINGS($T_A=25^{\circ}\text{C}$, RH=45%-75%, unless otherwise noted)

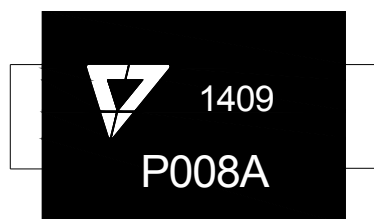
Parameter	Symbol	Value	Unit
Storage temperature range	T_{STG}	-60 to +150	$^{\circ}\text{C}$
Operating junction temperature range	T_J	-40 to +125	$^{\circ}\text{C}$
Repetitive peak pulse current	I_{PP}	35	A

ELECTRICAL CHARACTERISTICS($T_A=25^{\circ}\text{C}$)

Symbol	Parameter
V_{DRM}	Peak off-state voltage
I_{DRM}	Off-state current
V_S	Switching voltage
I_S	Switching current
V_T	On-state voltage
I_T	On-state current
I_H	Holding current
C_O	Off-state capacitance



MARKING



P008A : Device Marking Code
1409: In ninth week, 2014

ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$, continued)

Part Number	$I_{\text{DRM}}@V_{\text{DRM}}$		$V_S^{①}@I_S$		$V_T@I_T$		I_H	$C_O^{②}$	Marking
	μA	V	V	mA	V	A	mA	pF	
	max	min	max	max	max	max	min	max	
P0080TA	1	6	15	800	4	2.2	50	30	P008A
P0150TA	1	12	35	800	4	2.2	45	125	P015A
P0220TA	1	15	35	800	4	2.2	50	100	P022A
P0300TA	1	25	40	800	4	2.2	50	100	P030A

① V_S is measured at 100KV/s

② Off-state capacitance is measured in $V_{\text{DC}}=2\text{V}, V_{\text{RMS}}=1\text{V}, f=1\text{MHz}$

SURGE RATINGS

Series	$I_{\text{PP}}(\text{A})$ min			
	$2\times 10\mu\text{s}$	$8\times 20\mu\text{s}$	$10\times 360\mu\text{s}$	$10\times 1000\mu\text{s}$
A	100	90	50	35

ORDERING INFORMATION

P	008	0	T	A
Series code P: SIDACtor	Median voltage	0: Bi-direction 1: Uni-direction	Package type:SMA	Surge ratings:2KV(10/700 μs)

SOLDERING PARAMETERS

Reflow Condition		Pb-Free assembly (see FIG.2)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150°C
	-Temperature Max($T_{s(max)}$)	+200°C
	-Time (Min to Max) (t_s)	60-180 secs.
Average ramp up rate (Liquidus Temp (T_L) to peak)		3°C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L) (Liquidus)	+217°C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_p)		30secs. Max
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (T_P)		8 min. Max
Do not exceed		+260°C

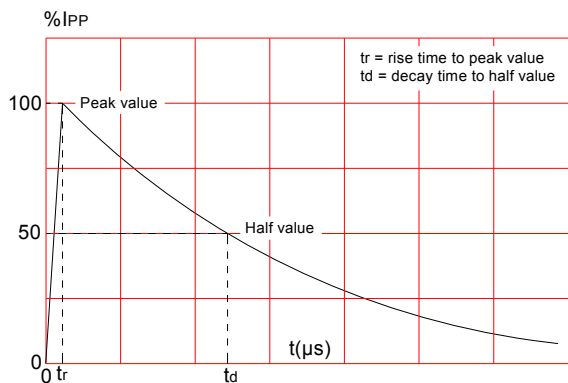
FIG.1: $t_r \times t_d$ pulse waveform

FIG.2: Reflow condition

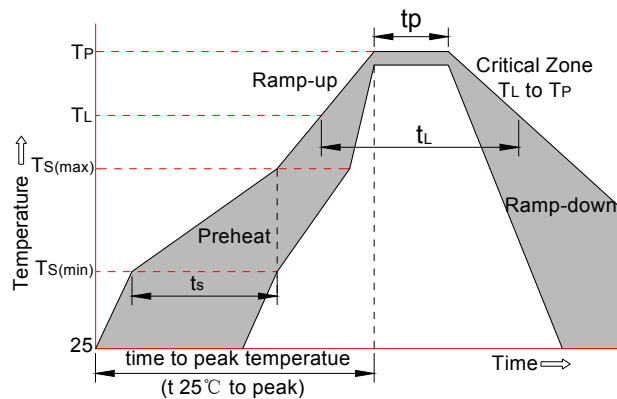
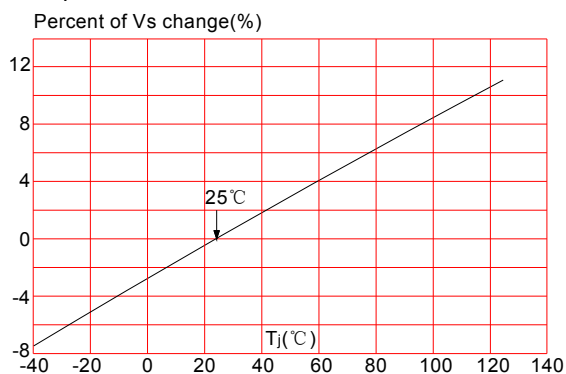
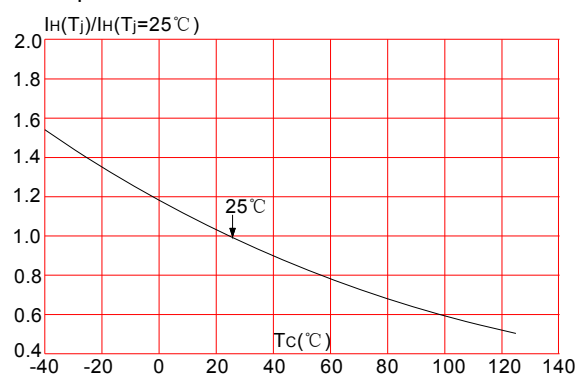
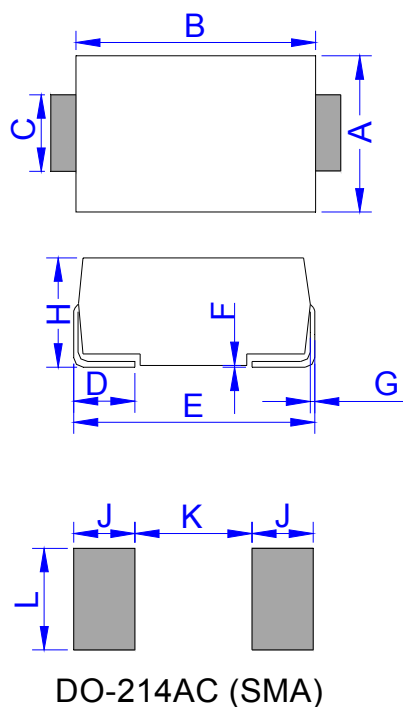
FIG.3: Normalized V_s change vs. junction temperature

FIG.4: Normalized DC holding current vs. case temperature

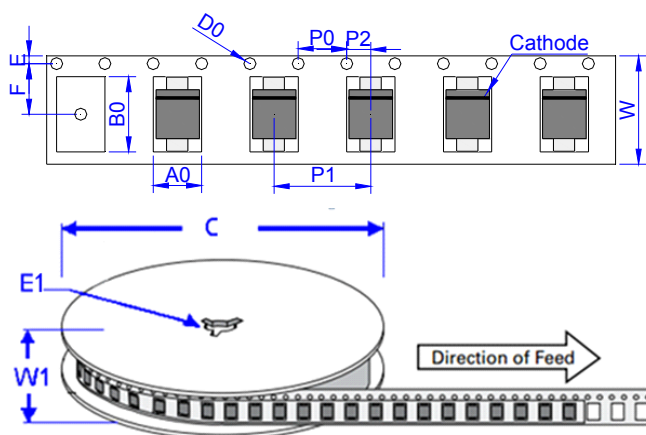


PACKAGE MECHANICAL DATA



Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	2.60	3.00	0.102	0.118
B	4.15	4.65	0.163	0.183
C	1.25	1.65	0.049	0.065
D	0.95	1.52	0.037	0.060
E	4.90	5.30	0.193	0.209
F	0.051	0.203	0.002	0.008
G	0.15	0.31	0.006	0.012
H	2.00	2.44	0.079	0.096
J	2.00		0.079	
K		2.30		0.091
L	1.80		0.071	

TAPE AND REEL SPECIFICATION-SMA



Ref.	Dimensions	
	Millimeters	Inches
A0	2.79 ± 0.3	0.110 ± 0.012
B0	5.33 ± 0.3	0.210 ± 0.012
C	330.0	13.0
D0	1.55 ± 0.1	0.061 ± 0.004
E	1.75 ± 0.2	0.069 ± 0.008
E1	13.3 ± 0.3	0.524 ± 0.012
F	5.5 ± 0.2	0.217 ± 0.008
P0	4.00 ± 0.2	0.157 ± 0.008
P1	4.00 ± 0.2	0.157 ± 0.008
P2	2.00 ± 0.2	0.079 ± 0.008
W	12.0 ± 0.2	0.472 ± 0.008
W1	15.7 ± 2.0	0.618 ± 0.079

OUTLINE	UNIT WEIGHT (g/PCS) typ.	REEL (PCS)	PER CARTON (PCS)	REEL DIAMETERS (mm)
TAPING	0.069	5,000	80,000	330

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